

Electrical Characterization of Organic Conducting Polymers

Lindsay Windsor

Cornell University

Class of 2007

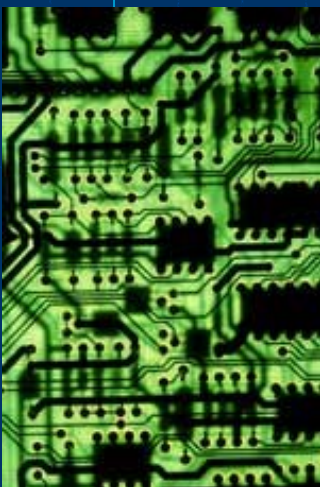
July 27, 2005



Molecular Devices:

Semiconductors of the near future

- Semiconductor technology continues to increase in complexity and decrease in size
- Soon silicon will be unable to meet market demands for small devices

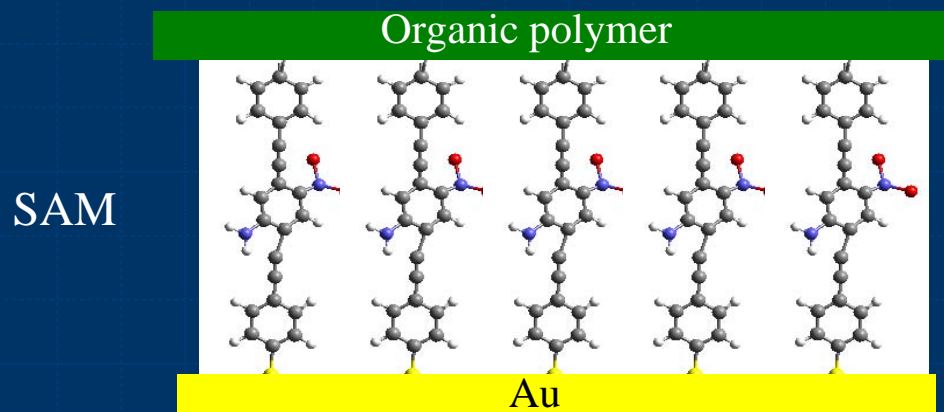


- Molecular devices could promote technological advance by creating smaller, more complex devices than are possible with silicon



Electrical Characterization of Self-Assembled Monolayers (SAM)

- Individual molecules as conductors, switches, and memory devices
- Self-assembly technique used for determining behavior of single layer of molecules or even single molecules

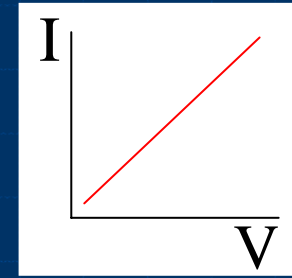


- Organic top contact optimal for integrity of device measurements

Previous work

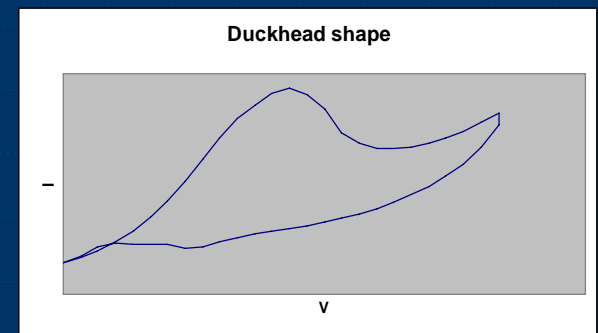
Electrical characterization of other organic polymers

- generally linear I-V curve on large scale
- some switching behavior for low-temperature measurements
- believed to be good, consistent conductors in thin films



Electrical characterization of PEDOT

- John Suehle's group found switching behavior between two conductive states
- Nonlinear hysteresis loop called "duckhead"TM



Summer Objectives

1. Identify a new organic conducting polymer and characterize its electrical properties (parallel study with PEDOT)

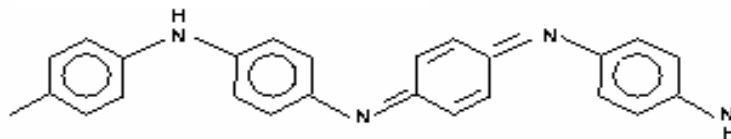
2. Linear behavior: use the new conducting polymer as the top electrode for SAM characterizations

2. Nonlinear behavior: investigate the behavior and conduction mechanism

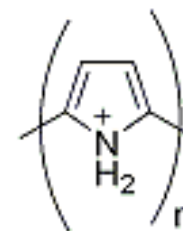
Two Polymer Candidates

Polyaniline (PANI)

Chemical structure:



Polypyrrole (PPy)

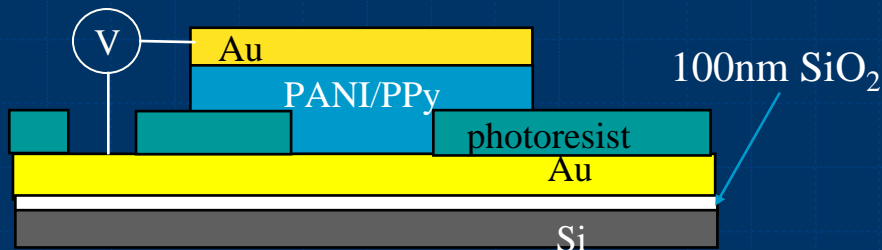


(doped with proprietary
organic sulfonic acid)

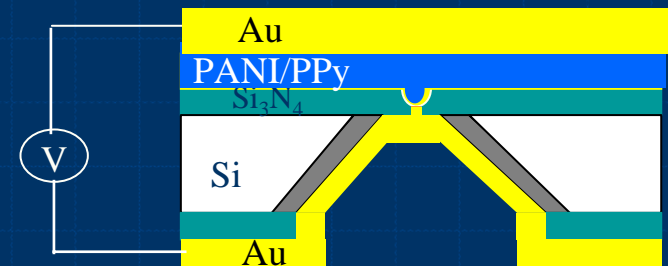
Advantages of these particular polymers:

- commercially available
- well-known as conductive polymers
- relatively environmentally stable
- some background information available in literature

Device Structure and Fabrication



Micron-size testbed



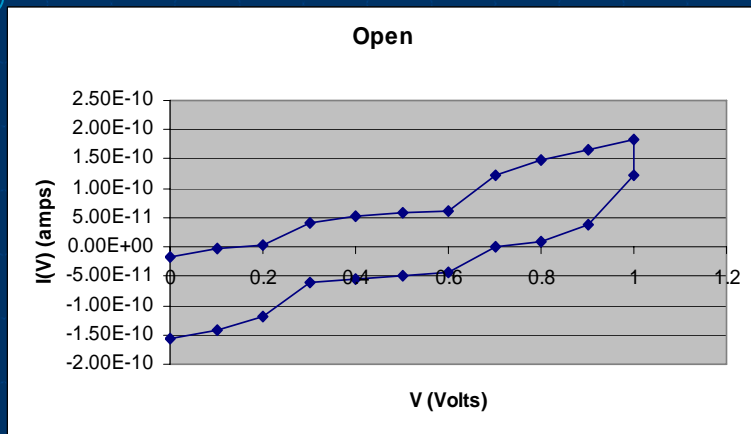
Nanopore

Micron-size Fabrication process:

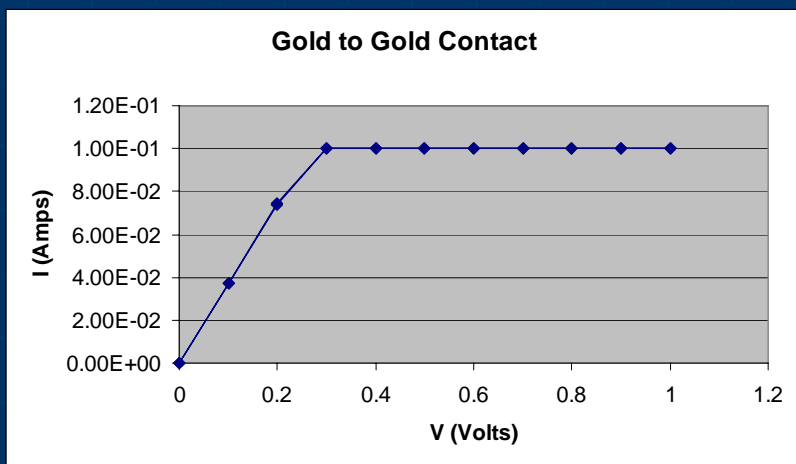
- Use silicon wafer coated with $\text{SiO}_2/\text{Si}_3\text{N}_4$
- Spin-on condition: 400 rpm for 5 s; 2500 rpm for 45s
 PANI thickness: $\sim 6000 \text{ \AA}$, PPy thickness : $\sim 1000 \text{ \AA}$
- Photoresist as the insulating layer
- Baked at 50°C for 3 hours
- Top Au metalization: shadowmask, $\sim 1200 \text{ \AA}$ @ 1 \AA/s
- O_2 plasma to etch off the uncovered PPy/PANI

Measurement Setup

Open



Short

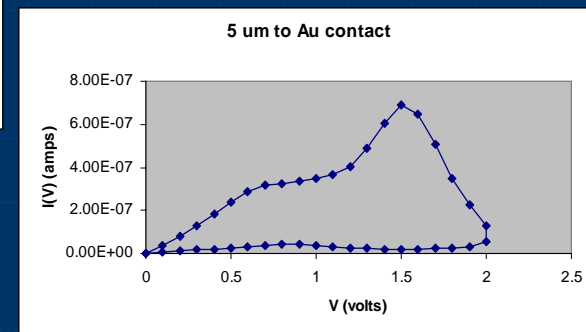
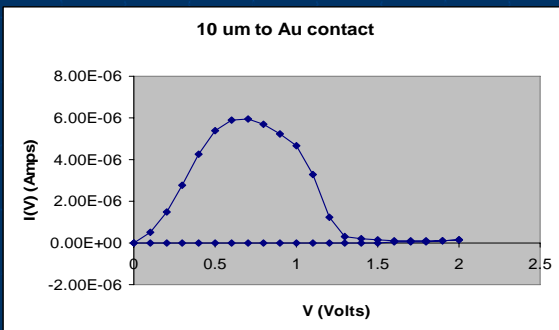
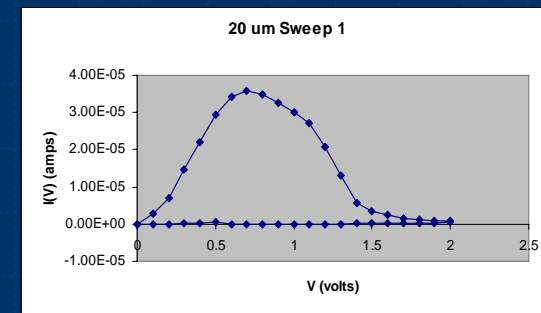
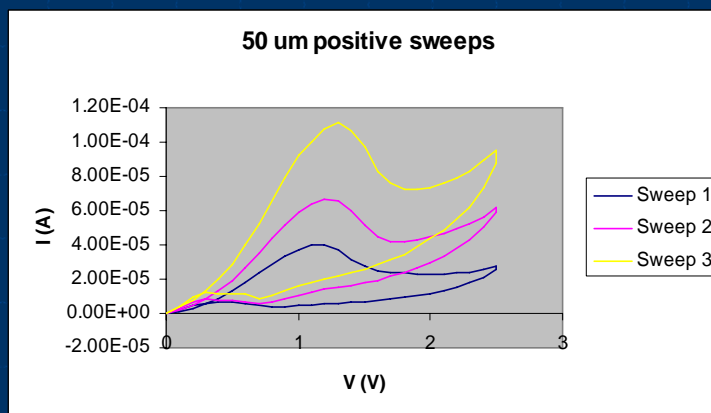
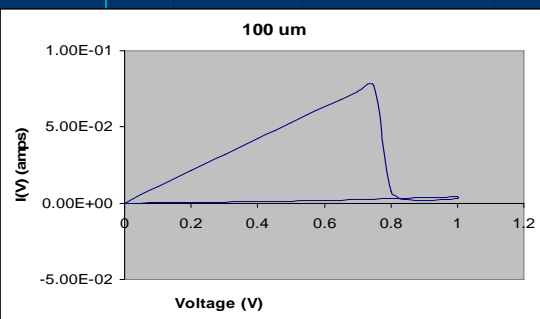


Results Summary:

1. PPy Micron-Sized Device – nonlinear I-V curve, degradation, area-dependence
2. PPy Nanopore Device – temperature dependence and conduction mechanism
3. PANI Nanopores – nonlinear I-V curve, degradation, and higher conduction than PPy

PPy Micron Device Results

- Nonlinear hysteresis for area smaller than 100 by 100 μm device
- Device degradation for positive sweeps greater than 0.6 V
- Nonlinear behavior and degradation for negative sweeps as well



Similar nonlinear I-V curve for PPy nanopore devices

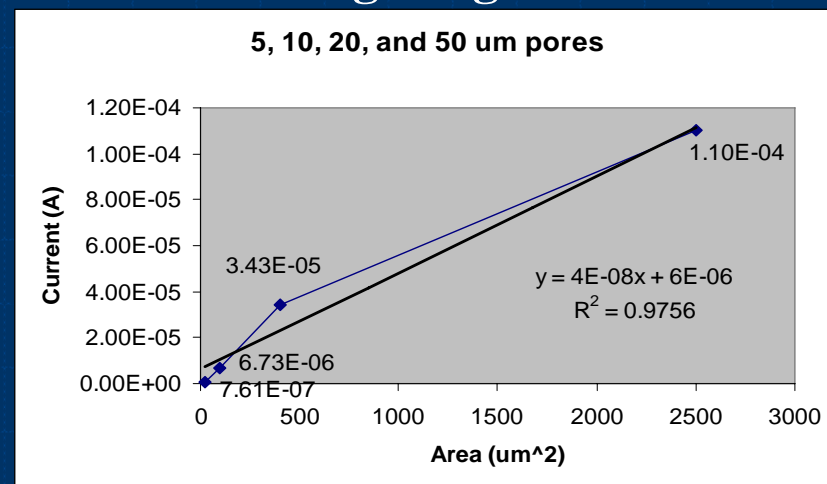
PPy Area Dependence

Constant current density of $\sim 4\text{E-}8 \text{ A/um}^2$

Current Density (A/um^2):

Device	5 um	10 um	20 um	50 um
A	3.41E-08	6.34E-08	8.93E-08	1.61E-08
B	3.36E-08	6.26E-08	6.90E-08	7.16E-08
C	2.92E-08	5.96E-08	9.90E-08	
D	2.76E-08	7.29E-08	8.55E-08	
E	2.76E-08	7.21E-08	8.93E-08	
F		6.84E-08	8.05E-08	
G		7.20E-08	8.75E-08	
Avg	3.04E-08	6.73E-08	8.58E-08	4.40E-08

Area v. Average Highest Current



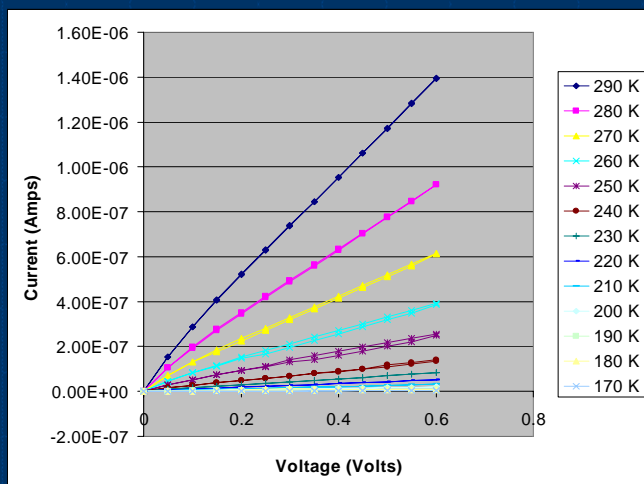
PPy Nanopore Temperature-Dependence



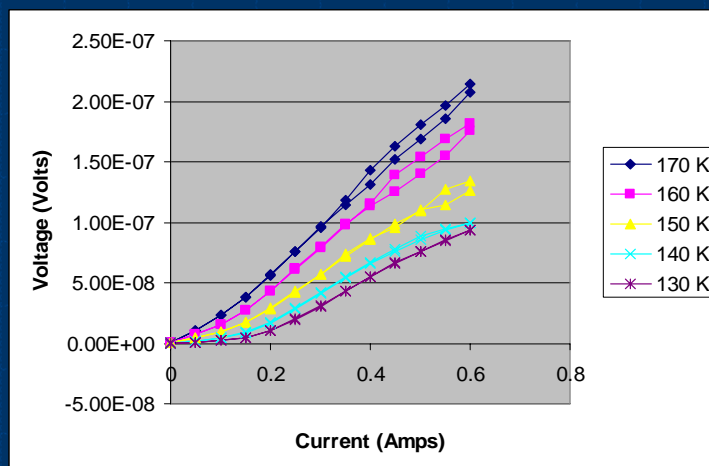
Measured four nanopore devices in cryostat, decreasing in temperature from 290 to 70 K, in order to determine the conduction mechanism

Typical Measurement Results

290 to 180 K



170 to 130 K



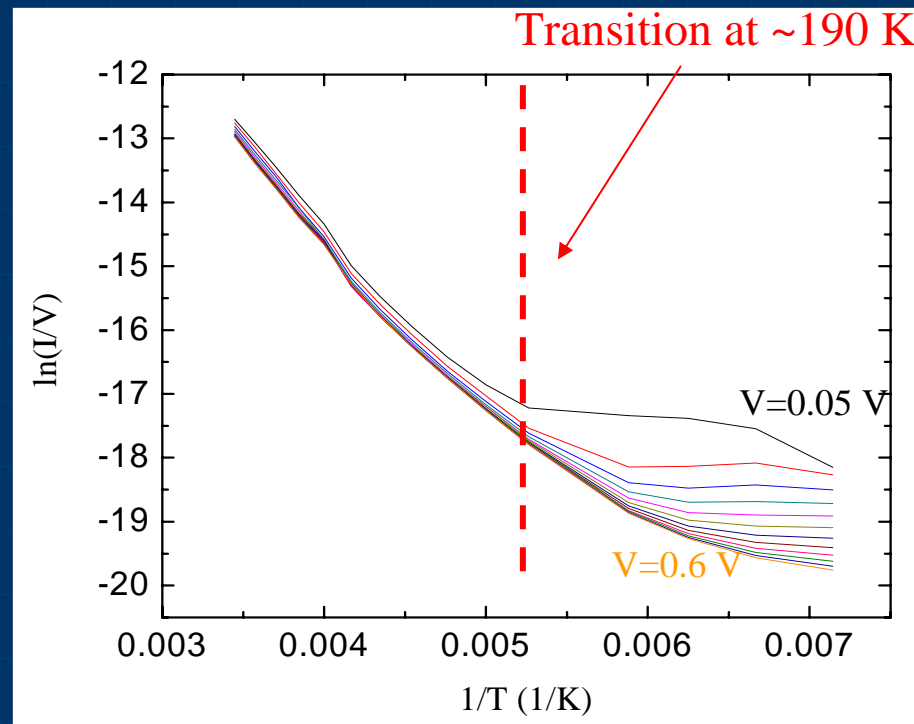
- Current decreases with decreasing temperature
- Temperature-dependent nonlinear behavior

Possible Conduction Mechanisms

	Conduction Mechanism	Characteristic Behavior	Temperature Dependence	Voltage Dependence
Tunneling no T-dependence	Direct Tunneling	$J \sim V \exp\left(-\frac{2d}{\hbar} \sqrt{2m\Phi}\right)$	none	$J \sim V$
	Fowler-Nordheim Tunneling	$J \sim V^2 \exp\left(-\frac{4d\sqrt{2m}\Phi^{3/2}}{3q\hbar V}\right)$	none	$\ln\left(\frac{J}{V^2}\right) \sim \frac{1}{V}$
Thermal activation T-dependence	Thermionic Emission	$J \sim T^2 \exp\left(-\frac{\Phi - q\sqrt{qV/4\pi\epsilon d}}{kT}\right)$	$\ln\left(\frac{J}{T^2}\right) \sim \frac{1}{T}$	$\ln(J) \sim V^{\frac{1}{2}}$
	Hopping Conduction	$J \sim V \exp\left(-\frac{\Phi}{kT}\right)$	$\ln\left(\frac{J}{V}\right) \sim \frac{1}{T}$	$J \sim V$

Hopping Conduction Analysis:

$$I \sim V \exp\left(-\frac{\Phi}{kT}\right)$$



Average barrier height:

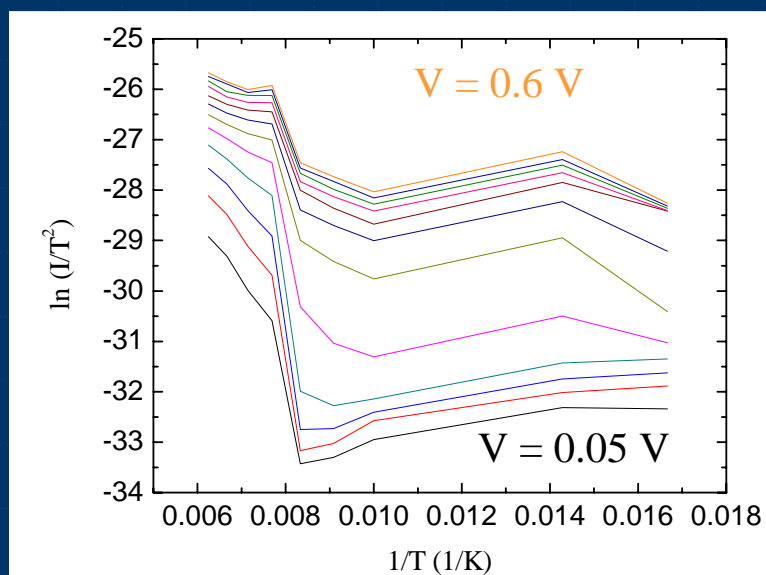
$$\overline{\Phi}_{\text{hopping}} = 100 \text{ to } 200 \text{ meV}$$

Other Conduction Mechanism?

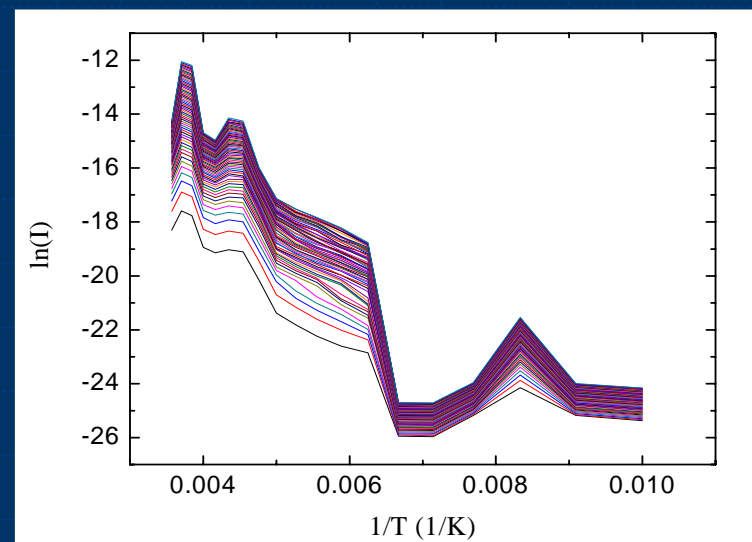
T from 170 to 60K

Thermionic Emission

$$I \sim T^2 \exp\left(-\frac{\Phi - q\sqrt{qV / 4\pi\epsilon d}}{kT}\right)$$



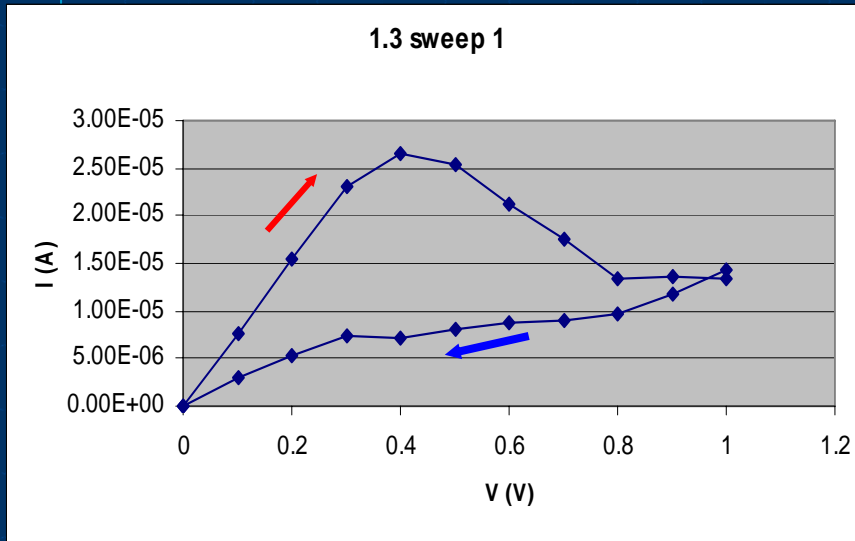
Arrhenius Analysis



Data graphed from 0.01 V to 0.6 V in increments of 0.01 V

Need further investigation to understand this transition behavior

PANI Nanopores



16 duckhead devices, 66.7%



Resistivity Measurement

Polypyrrole: 793 S/cm

Polyaniline: 526 S/cm

These values are reasonable: our results agree with published resistivity measurements to within an order of magnitude

Summary of Conclusions:

- Both PANI and PPy have *nonlinear hysteresis loops* for their I-V curves on small-scale devices
- Devices *degrade for high bias sweeps*, and degrade even more with switched direction of bias sweep
- The current of PPy exhibits *area dependence, sweep rate dependence, and temperature dependence*
- *Hopping conduction* is the conduction mechanism in PPy for $T > 190$ K; conduction transition at 190 K, still T-dependent but not Thermionic Emission
- PANI yields a much *higher current* than PPy

Summer Objectives

1. Identify a new organic conducting polymer and characterize its electrical properties (parallel study with PEDOT)

2. Linear behavior: use the new conducting polymer as the top electrode for SAM characterizations

2. Nonlinear behavior: investigate the behavior and conduction mechanism

Summer Objectives

1. Identify a new organic conducting polymer and characterize its electrical properties (parallel study with PEDOT)

~~**2. Linear behavior: use the new conducting polymer as the top electrode for SAM characterizations**~~

2. Nonlinear behavior: investigate the behavior and conduction mechanism

With nonlinear behavior,
conducting polymer makes
poor top contact for SAM

Summer Objectives

1. Identify a new organic conducting polymer and characterize its electrical properties (parallel study with PEDOT)

2. Nonlinear behavior: investigate the behavior and conduction mechanism

Future work for characterizing the electrical properties of these polymers:

- *Understand conduction mechanisms* in PPy below 190 K, PANI
- *Theoretical basis* for experimental switching results in both PANI and PPy
- Greater accuracy in resistivity value, hopping barriers, control measurement, etc.

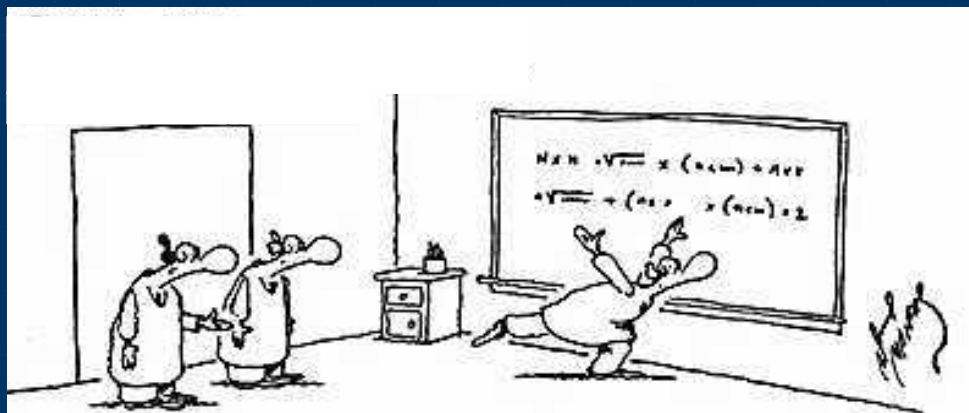
Acknowledgements

Wenyong Wang, Curt Richter, John Suehle,
Oleg Kirillov and Eric Vogel

Society of Physics Students

Liz Dart Caron and Gary White

National Institute of Standards and Technology



“At some point the theory becomes so abstract it can only be conveyed using interpretive dance”